SCAS029A - JULY 1987 - REVISED APRIL 1993

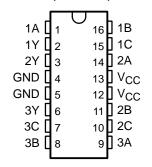
- Flow-Through Architecture Optimizes
 PCB Layout
- Center-Pin V_{CC} and GND Configuration Minimizes High-Speed Switching Noise
- EPIC[™] (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

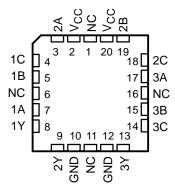
These devices contain three independent 3-input AND gates. They perform the Boolean functions $Y = A \cdot B \cdot C$ or $Y = \overline{A} + \overline{B} + \overline{C}$ in positive logic.

The 54AC11011 is characterized for operation over the full military temperature range of -55°C to 125°C. The 74AC11011 is characterized for operation from -40°C to 85°C.

54AC11011 . . . J PACKAGE 74AC11011 . . . D OR N PACKAGE (TOP VIEW)



54AC11011 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE (each gate)

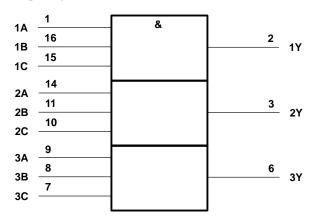
	INPUTS	ОИТРИТ	
Α	В	С	Y
Н	Н	Н	Н
L	X	Χ	L
Х	L	Χ	L
Х	Χ	L	L

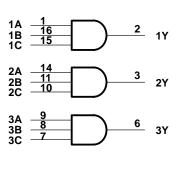
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SCAS029A - JULY 1987 - REVISED APRIL 1993

logic symbol†

logic diagram (positive logic)





Pin numbers shown are for the D, J, and N packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Storage temperature range	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

recommended operating conditions

			54	AC1101	1	74AC11011		UNIT	
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
VCC	Supply voltage		3	5	5.5	3	5	5.5	V
		V _{CC} = 3 V	2.1			2.1			
VIН	High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			
		V _{CC} = 5.5 V	3.85			3.85			
		V _{CC} = 3 V			0.9			0.9	
V _{IL}	Low-level input voltage	$V_{CC} = 4.5 V$			1.35			1.35	V
		V _{CC} = 5.5 V			1.65			1.65	
٧ _I	Input voltage				VCC	0		VCC	V
۷o	Output voltage		0		VCC	0		VCC	V
		V _{CC} = 3 V			-4			-4	
IОН	High-level output current	$V_{CC} = 4.5 \text{ V}$			-24			-24	mA
		$V_{CC} = 5.5 \text{ V}$			-24			-24	
		V _{CC} = 3 V			12			12	
lOL	Low-level output current	V _{CC} = 4.5 V			24			24	mA
		V _{CC} = 5.5 V			24			24	
Δt/Δν	Input transition rise or fall rate		0		10	0		10	ns/V
TA	Operating free-air temperature		-55		125	-40	,	85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		T,	<u> </u> = 25°C	;	54AC1	1011	74AC11011		LINUT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		3 V	2.9			2.9		2.9		
	I _{OH} = – 50 μA	4.5 V	4.4			4.4		4.4		
		5.5 V	5.4			5.4		5.4		
Vari	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.4		2.48		V
Vон		4.5 V	3.94			3.7		3.8		V
	$I_{OH} = -24 \text{ mA}$	5.5 V	4.94			4.7		4.8		
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V						3.85		
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
		4.5 V			0.1		0.1		0.1	
		5.5 V			0.1		0.1		0.1	
VOL	I _{OL} = 12 mA	3 V			0.36		0.5		0.44	V
VOL	I _{OL} = 24 mA	4.5 V			0.36		0.5		0.44	ľ
	10L - 24 111A	5.5 V			0.36		0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V					1.65			
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V							1.65	<u> </u>
lį	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		80		40	μΑ
Ci	V _I = V _{CC} or GND	5 V		3.5						рF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

SCAS029A - JULY 1987 - REVISED APRIL 1993

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то то		4 = 25°C	;	54AC1	11011	74AC1	1011	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	Any	V	1.5	6	8.3	1.5	9.7	1.5	9.1	20
^t PHL		ī	1.5	6	8.2	1.5	9.6	1.5	9	ns

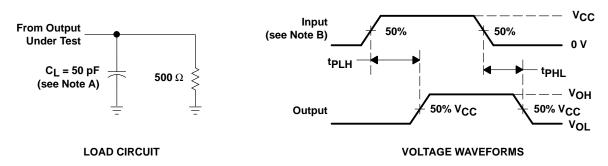
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	T,	գ = 25°C	;	54AC1	11011	74AC1	11011	UNIT
	(INPUT)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
t _{PLH}	Any	V	1.5	4	5.9	1.5	6.9	1.5	6.5	20
t _{PHL}	Any	ī	1.5	4.5	6.4	1.5	7.3	1.5	6.9	ns

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per gate	$C_L = 50 \text{ pF}, f = 1 \text{ MHz}$	28	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f = 3 \text{ ns}$, $t_f = 3 \text{ ns}$.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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